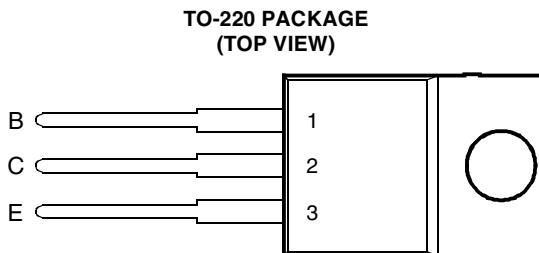


- Designed for Complementary Use with BDX33, BDX33A, BDX33B, BDX33C and BDX33D
- 70 W at 25°C Case Temperature
- 10 A Continuous Collector Current
- Minimum h_{FE} of 750 at 3V, 3 A



This series is currently available, but not recommended for new designs.



Pin 2 is in electrical contact with the mounting base.

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absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT
Collector-base voltage ($I_E = 0$)	BDX34	V_{CBO}	-45	V
	BDX34A		-60	
	BDX34B		-80	
	BDX34C		-100	
	BDX34D		-120	
Collector-emitter voltage ($I_B = 0$)	BDX34	V_{CEO}	-45	V
	BDX34A		-60	
	BDX34B		-80	
	BDX34C		-100	
	BDX34D		-120	
Emitter-base voltage		V_{EBO}	-5	V
Continuous collector current		I_C	-10	A
Continuous base current		I_B	-0.3	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 1)		P_{tot}	70	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 2)		P_{tot}	2	W
Operating free air temperature range		T_J	-65 to +150	°C
Storage temperature range		T_{stg}	-65 to +150	°C
Operating free-air temperature range		T_A	-65 to +150	°C

NOTES: 1. Derate linearly to 150°C case temperature at the rate of 0.56 W/°C.

2. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

PRODUCT INFORMATION

electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$ Collector-emitter breakdown voltage	$I_C = -100 \text{ mA}$	$I_B = 0$	(see Note 3)	BDX34 BDX34A BDX34B BDX34C BDX34D	-45 -60 -80 -100 -120		V
I_{CEO} Collector-emitter cut-off current	$V_{CE} = -30 \text{ V}$	$I_B = 0$		BDX34		-0.5	
	$V_{CE} = -30 \text{ V}$	$I_B = 0$		BDX34A		-0.5	
	$V_{CE} = -40 \text{ V}$	$I_B = 0$		BDX34B		-0.5	
	$V_{CE} = -50 \text{ V}$	$I_B = 0$		BDX34C		-0.5	
	$V_{CE} = -60 \text{ V}$	$I_B = 0$		BDX34D		-0.5	
	$V_{CE} = -30 \text{ V}$	$I_B = 0$	$T_C = 100^\circ\text{C}$	BDX34		-10	
	$V_{CE} = -30 \text{ V}$	$I_B = 0$	$T_C = 100^\circ\text{C}$	BDX34A		-10	
	$V_{CE} = -40 \text{ V}$	$I_B = 0$	$T_C = 100^\circ\text{C}$	BDX34B		-10	
	$V_{CE} = -50 \text{ V}$	$I_B = 0$	$T_C = 100^\circ\text{C}$	BDX34C		-10	
	$V_{CE} = -60 \text{ V}$	$I_B = 0$	$T_C = 100^\circ\text{C}$	BDX34D		-10	
I_{CBO} Collector cut-off current	$V_{CB} = -45 \text{ V}$	$I_E = 0$		BDX34		-1	
	$V_{CB} = -60 \text{ V}$	$I_E = 0$		BDX34A		-1	
	$V_{CB} = -80 \text{ V}$	$I_E = 0$		BDX34B		-1	
	$V_{CB} = -100 \text{ V}$	$I_E = 0$		BDX34C		-1	
	$V_{CB} = -120 \text{ V}$	$I_E = 0$		BDX34D		-1	
	$V_{CB} = -45 \text{ V}$	$I_E = 0$	$T_C = 100^\circ\text{C}$	BDX34		-5	
	$V_{CB} = -60 \text{ V}$	$I_E = 0$	$T_C = 100^\circ\text{C}$	BDX34A		-5	
	$V_{CB} = -80 \text{ V}$	$I_E = 0$	$T_C = 100^\circ\text{C}$	BDX34B		-5	
	$V_{CB} = -100 \text{ V}$	$I_E = 0$	$T_C = 100^\circ\text{C}$	BDX34C		-5	
	$V_{CB} = -120 \text{ V}$	$I_E = 0$	$T_C = 100^\circ\text{C}$	BDX34D		-5	
I_{EBO} Emitter cut-off current	$V_{EB} = -5 \text{ V}$	$I_C = 0$				-10	mA
h_{FE} Forward current transfer ratio	$V_{CE} = -3 \text{ V}$	$I_C = -4 \text{ A}$		BDX34	750		
	$V_{CE} = -3 \text{ V}$	$I_C = -4 \text{ A}$		BDX34A	750		
	$V_{CE} = -3 \text{ V}$	$I_C = -3 \text{ A}$	(see Notes 3 and 4)	BDX34B	750		
	$V_{CE} = -3 \text{ V}$	$I_C = -3 \text{ A}$		BDX34C	750		
	$V_{CE} = -3 \text{ V}$	$I_C = -3 \text{ A}$		BDX34D	750		
$V_{BE(on)}$ Base-emitter voltage	$V_{CE} = -3 \text{ V}$	$I_C = -4 \text{ A}$		BDX34		-2.5	
	$V_{CE} = -3 \text{ V}$	$I_C = -4 \text{ A}$		BDX34A		-2.5	
	$V_{CE} = -3 \text{ V}$	$I_C = -3 \text{ A}$	(see Notes 3 and 4)	BDX34B		-2.5	
	$V_{CE} = -3 \text{ V}$	$I_C = -3 \text{ A}$		BDX34C		-2.5	
	$V_{CE} = -3 \text{ V}$	$I_C = -3 \text{ A}$		BDX34D		-2.5	
$V_{CE(sat)}$ Collector-emitter saturation voltage	$I_B = -8 \text{ mA}$	$I_C = -4 \text{ A}$		BDX34		-2.5	
	$I_B = -8 \text{ mA}$	$I_C = -4 \text{ A}$		BDX34A		-2.5	
	$I_B = -6 \text{ mA}$	$I_C = -3 \text{ A}$	(see Notes 3 and 4)	BDX34B		-2.5	
	$I_B = -6 \text{ mA}$	$I_C = -3 \text{ A}$		BDX34C		-2.5	
	$I_B = -6 \text{ mA}$	$I_C = -3 \text{ A}$		BDX34D		-2.5	
V_{EC} Parallel diode forward voltage	$I_E = -8 \text{ A}$	$I_B = 0$				-4	V

NOTES: 3. These parameters must be measured using pulse techniques, $t_p = 300 \mu\text{s}$, duty cycle $\leq 2\%$.

4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

PRODUCT INFORMATION

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thermal characteristics

PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			1.78	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W

resistive-load-switching characteristics at 25°C case temperature

PARAMETER	TEST CONDITIONS [†]			MIN	TYP	MAX	UNIT
t_{on}	$I_C = -3 A$	$I_{B(on)} = -12 mA$	$I_{B(off)} = 12 mA$		1		μs
t_{off}	$V_{BE(off)} = 3.5 V$	$R_L = 10 Ω$	$t_p = 20 μs, dc \leq 2\%$		5		μs

[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

PRODUCT INFORMATION

TYPICAL CHARACTERISTICS

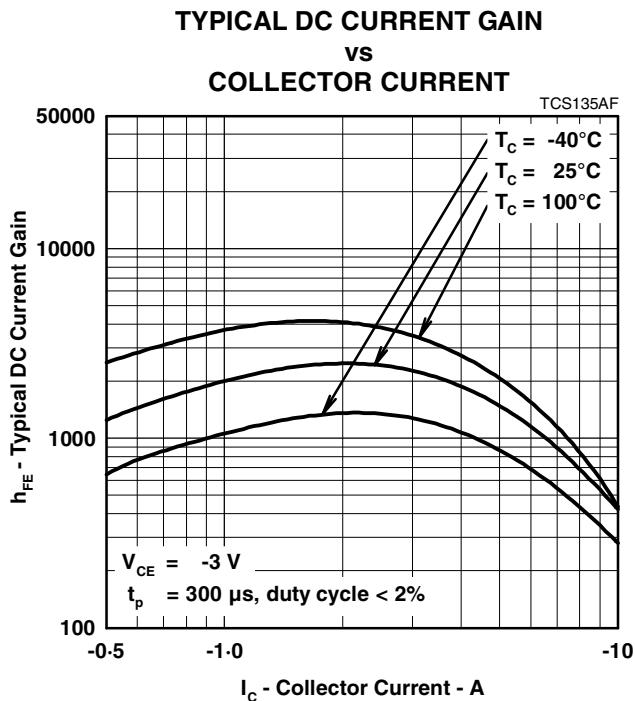


Figure 1.

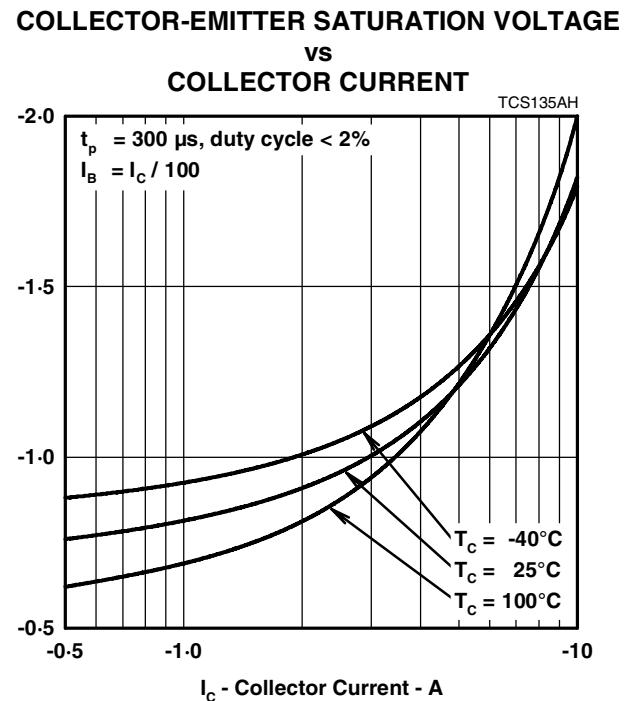


Figure 2.

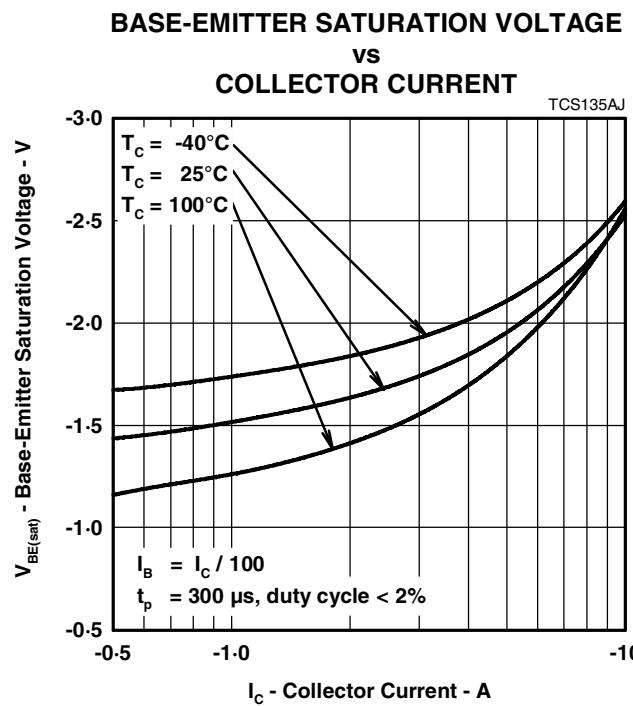
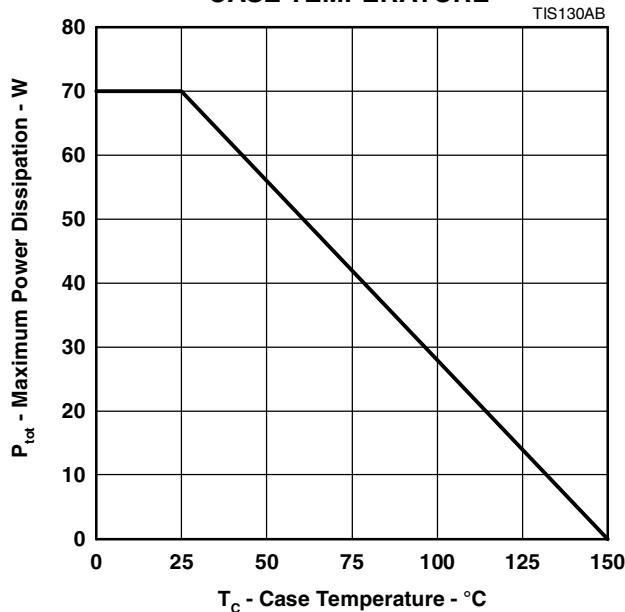


Figure 3.

PRODUCT INFORMATION

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THERMAL INFORMATION**MAXIMUM POWER DISSIPATION
VS
CASE TEMPERATURE****Figure 4.****PRODUCT INFORMATION**

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